













ESD

TVS

TSS

MOV

GDT

PLED

SS22B THRU SS210B

Product specification





Features

- Ideal for surface mount applications
- Easy pick and place
- Built-in strain relief
- Low forward voltage drop

MECHANICAL DATA

- Case: Molded plastic
- Epoxy: UL 94V-0 rate flame retardant
- Metallurgically bonded construction
- Polarity: Color band denotes cathode end
- Mounting position: Any
- Weight: 0.093 grams

Reference News

PACKAGE OUTLINE	Pin Configuration		
A CONTRACTOR OF A CONTRACTOR O			
DO-214AA(SMB)			



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25 C ambient temperature unless otherwies specified . Single phase half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

TYPE NUMBER	SS22B	SS23B	SS24B	SS25B	SS26B	SS28B	SS29B	SS210B	UNITS
Maximum Recurrent Peak Reverse Voltage	20	30	40	50	60	80	90	100	V
Maximum RMS Voltage	14	21	28	35	42	56	63	70	V
Maximum DC Blocking Voltage	20	30	40	50	60	80	90	100	V
Maximum Average Forward Rectified Current			I	1	I	1			
See Fig. 1	2.0						А		
Peak Forward Surge Current, 8.3 ms single half									
sine-wave superimposed on rated load (JEDEC	50						А		
method)									
Maximum Instantaneous Forward Voltage at 2.0A		0.55 0.70			0.85			V	
Maximum DC Reverse Current	0.1 0.02					mA			
at Rated DC Blocking Voltage	5 2				mA				
Typical Junction Capacitance (Note1)	170				pF				
Typical Thermal Resistance R JA (Note 2)	75				C/W				
Operating Temperature Range T _J	-65 +150				°C				
Storage Temperature Range Tsто	-65 +150					°C			

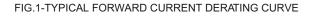
NOTES:

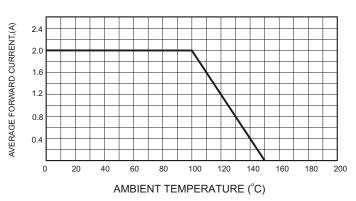
1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal Resistance Junction to Ambient.



RATINGAND CHARACTERISTIC CURVES (SS22 THRU SS210)







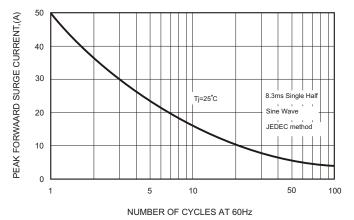


FIG.4-TYPICAL JUNCTION CAPACITANCE

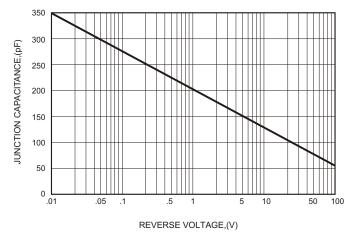


FIG.2-TYPICAL FORWARD

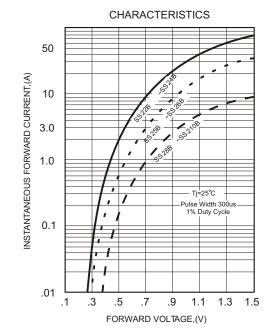
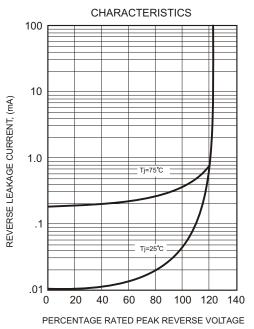
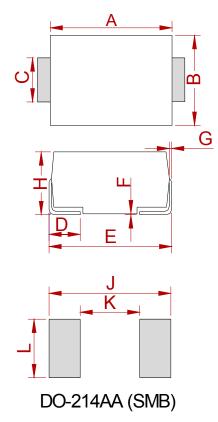


FIG.5 - TYPICAL REVERSE





PACKAGE MECHANICAL DATA



	Dimensions					
Ref.	Millimeters		Inches			
	Min.	Max.	Min.	Max.		
Α	4.25	4.75	0.167	0.187		
В	3.30	3.94	0.130	0.155		
С	1.85	2.21	0.073	0.087		
D	0.76	1.52	0.030	0.060		
E	5.08	5.59	0.200	0.220		
F	0.051	0.203	0.002	0.008		
G	0.15	0.31	0.006	0.012		
Н	2.11	2.44	0.083	0.096		
J	6.80		0.270			
К		2.60		0.100		
L	2.40		0.090			

REEL SPECIFICATION

P/N	PKG	QTY
SS22B THRU SS210B	SMB	3000



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